

Vishay Siliconix

P-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	r _{DS(on)} (Ω)	I _D (A)		
- 30	0.0085 at V _{GS} = - 10 V	- 14		
	0.014 at V _{GS} = - 4.5 V	- 11		

FEATURES

• TrenchFET[®] Power MOSFET

7100 Ω

P-Channel

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• ESD Protection: 3000 V

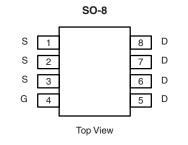
APPLICATIONS

- Notebook PC
- Load Switch

GC

- Adapter Switch





Ordering Information: Si4483EDY-T1-E3 (Lead (Pb)-free)

ABSOLUTE MAXIMUM RATINGS	$I_A = 25 ^{\circ}C$, unle	ess otherwise i	noted		
Parameter		Symbol	10 sec	Steady State	Unit
Drain-Source Voltage		V _{DS}	- 30		V
Gate-Source Voltage	oltage		± 25		v
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 25 °C	1	- 14	- 10	٨
	T _A = 70 °C	- I _D	- 11	- 8	
Pulsed Drain Current		I _{DM}	- 50		A
Continuous Source Current (Diode Conduction) ^a		۱ _S	- 2.7	- 1.36	
	T _A = 25 °C	D	3.0	1.5	w
Maximum Power Dissipation ^a	T _A = 70 °C	P _D	1.9	0.95	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
	$t \le 10 \text{ sec}$	R _{thJA}	33	42		
Maximum Junction-to-Ambient ^a	Steady State		70	85	°C/W	
Maximum Junction-to-Foot (Drain)	Steady State		16	21		

Notes:

a. Surface Mounted on 1" x 1" FR4 Board.



Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \ \mu A$	- 1.0		3.0	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 4.5 V$			± 1	μA	
		$V_{DS} = 0 V, V_{GS} = \pm 25 V$			± 10	mA	
Zero Gate Voltage Drain Current	I _{DSS} –	$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			- 1	μA	
		V_{DS} = - 30 V, V_{GS} = 0 V, T_{J} = 70 °C			- 10		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = -5 V, V_{GS} = -10 V$	- 30			А	
Drain-Source On-State Resistance ^a	r _{DS(on)}	V _{GS} = - 10 V, I _D = - 14 A		0.007	0.0085	Ω	
		V _{GS} = - 4.5 V, I _D = - 11 A		0.0115	0.014		
Forward Transconductance ^a	g _{fs}	V _{DS} = - 15 V, I _D = - 14 A		60		S	
Diode Forward Voltage ^a	V _{SD}	$I_{S} = -2.7 \text{ A}, V_{GS} = 0 \text{ V}$		- 0.74	- 1.1	V	
Dynamic ^b			•	•			
Turn-On Delay Time	t _{d(on)}			10	15		
Rise Time	t _r	V_{DD} = - 15 V, R_L = 15 Ω		20	30	1	
Turn-Off Delay Time	t _{d(off)}	$t_{d(off)}$ I _D \cong - 1 A, V _{GEN} = - 10 V, R _g = 6 Ω		42	65	μs	
Fall Time	t _f			50	80		

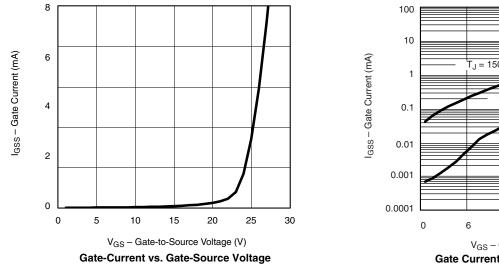
Notes:

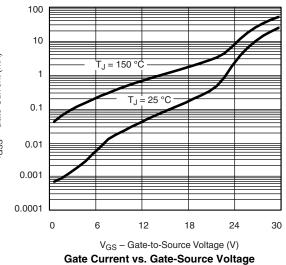
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



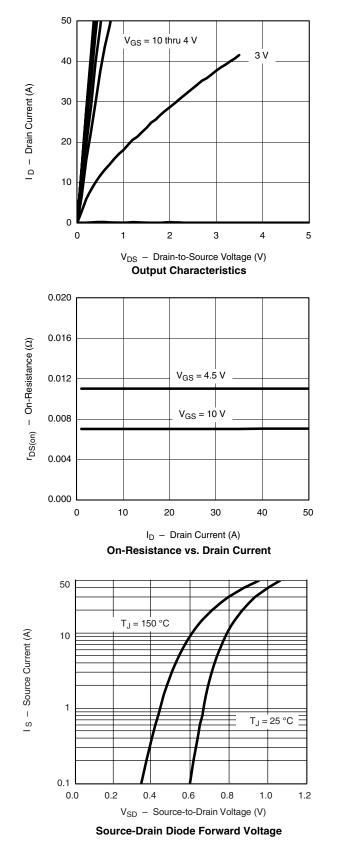


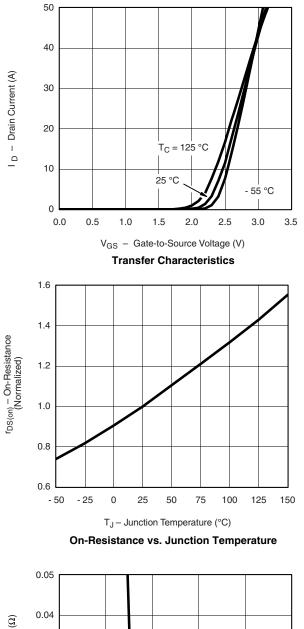


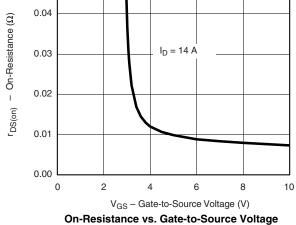
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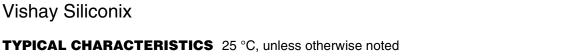


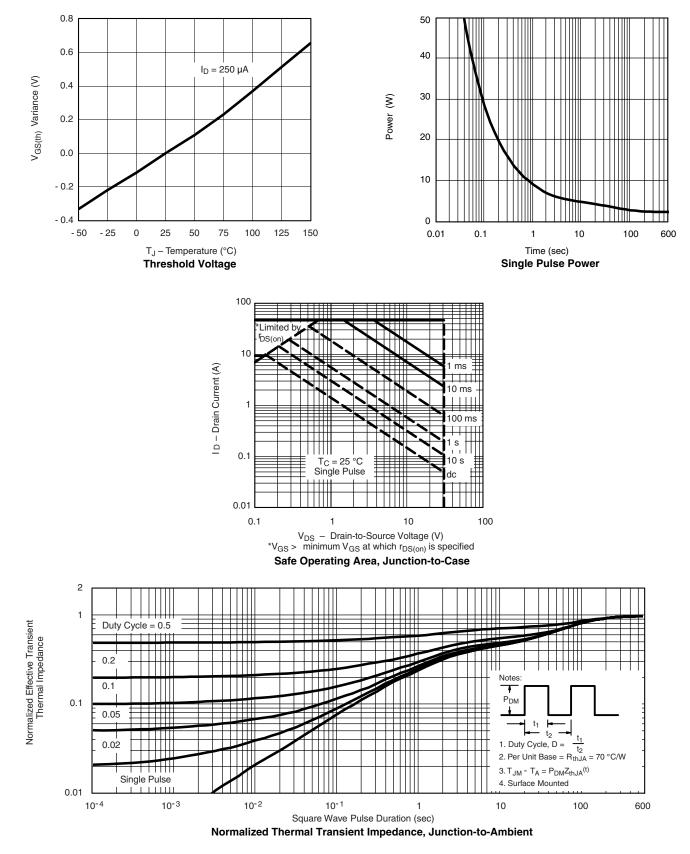




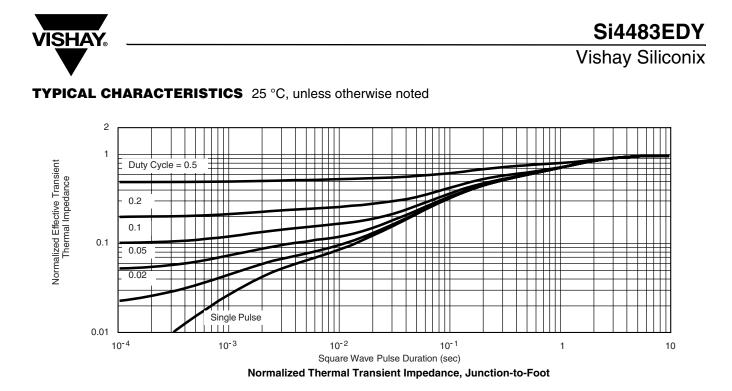
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Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?72862.



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